

Symbols and Terminology

A	anode Anode terminal	C_j	junction capacitance Capacitance due to a pn junction of a diode, decreases with increasing reverse voltage
A	ampere SI unit of electrical current	d	apparent (or virtual) source size (of an emitter) The measured diameter of an optical source used to calculate the eye safety laser class of the source. See IEC60825-1 and EN ISO 11146-1
A	radiant sensitive area That area which is radiant sensitive for a specified range	E	emitter Emitter terminal (phototransistor)
a	distance E.g. a distance between the emitter (source) and the detector	E_A	illumination at standard illuminant A According to DIN 5033 and IEC 306-1, illumination emitted from a tungsten filament lamp with a color temperature $T_f = 2855.6$ K, which is equivalent to standard illuminant A Unit: lx (Lux) or klx
B	base Base terminal	$E_{A\text{ amb}}$	ambient illumination at standard illuminant A
BER	Bit Error Rate	echo - off	Unprecise term to describe the behavior of the output of IrDA [®] transceivers during transmission. "echo – off" means that by blocking the receiver the output Rxd is quiet during transmission
bit/s	data rate or signaling rate 1000 bit/s = 1 kbit/s, 10^6 bit/s = 1 Mbit/s	echo - on	Unprecise term to describe the behavior of the output of IrDA [®] transceivers during transmission. "echo – on" means that the receiver output Rxd is active but often undefined during transmission. For correct data reception after transmission the receiver channel must be cleared during the latency period
C	capacitance Unit: F (farad) = C/V	E_e, E	irradiance (at a point of a surface) Quotient of the radiant flux $d\Phi_e$ incident on an element of the surface containing the point, by the area dA of that element. Equivalent definition. Integral, taken over the hemisphere visible from the given point, of the expression $L_e \cdot \cos\theta \cdot d\Omega$, where L_e is the radiance at the given point in the various directions of the incident elementary beams of solid angle $d\Omega$, and θ is the angle between any of these beams and the normal to the surface at the given point
C	coulomb $C = A \cdot s$		$E_e = \frac{d\Phi_e}{dA} = \int_{2\pi\text{sr}} (L_e \cdot \cos\theta \cdot d\Omega)$
C	cathode , cathode terminal		Unit: $W \cdot m^{-2}$
C	collector , collector terminal	E_v, E	illuminance (at a point of a surface) Quotient of the luminous flux $d\Phi_v$ incident on
°C	degree Celsius Celsius temperature, symbol t , and is defined by the quantity equation $t = T - T_0$. The unit of Celsius temperature is the degree Celsius, symbol °C. The numerical value of a Celsius temperature t expressed in degrees Celsius is given by $t / ^\circ\text{C} = T / \text{K} - 273.15$ It follows from the definition of t that the degree Celsius is equal in magnitude to the kelvin, which in turn implies that the numerical value of a given temperature difference or temperature interval whose value is expressed in the unit degree Celsius (°C) is equal to the numerical value of the same difference or interval when its value is expressed in the unit kelvin (K)		
cd	candela SI unit of luminous intensity. The candela is the luminous intensity, in a given direction, of a source that emits monochromatic radiation of frequency 540×10^{12} hertz and that has a radiant intensity in that direction of $1/683$ watt per steradian. (16 th General Conference of Weights and Measures, 1979) $1 \text{ cd} = 1 \text{ lm} \cdot \text{sr}^{-1}$		
C_D	diode capacitance Total capacitance effective between the diode terminals due to case, junction and parasitic capacitances		

an element of the surface containing the point, by the area dA of that element.

Equivalent definition. Integral, taken over the hemisphere visible from the given point, of the expression $L_v \cdot \cos \theta \cdot d\Omega$, where L_v is the luminance at the given point in the various directions of the incident elementary beams of solid angle $d\Omega$, and θ is the angle between any of these beams and the normal to the surface at the given point

$$E_v = \frac{d\Phi_v}{dA} = \int_{2\pi \text{sr}} (L_v \cdot \cos \theta \cdot d\Omega)$$

Unit: $\text{lx} = \text{lm} \cdot \text{m}^{-2}$

F farad

Unit: $F = \text{C/V}$

f frequency

Unit: s^{-1} , Hz (Hertz)

f_c, f_{cd} cut-off frequency – detector devices

The frequency at which, for constant signal modulation depth of the input radiant power, the demodulated signal power has decreased to $\frac{1}{2}$ of its low frequency value. Example: The incident radiation generates a photocurrent or a photo voltage 0.707 times the value of radiation at $f = 1 \text{ kHz}$

(3 dB signal drop, other references may occur as e.g. 6 dB or 10 dB)

f_s switching frequency

FIR Fast Infrared, as SIR, data rate 4 Mbit/s

I_a light current

General: Current which flows through a device due to irradiation/illumination

I_B base current

I_{BM} base peak current

I_C collector current

I_{ca} collector light current

Collector current under irradiation

Collector current which flows at a specified illumination/irradiation

I_{CEO} collector dark current, with open base

Collector-emitter dark current

For radiant sensitive devices with open base and without illumination/radiation ($E = 0$)

I_{CM} repetitive peak collector current

Mode of operation where the device (e.g. a transceiver) is fully operational and expecting to receive a signal for operation e.g. in case of a transceiver waiting to receive an optical input

or to send an optical output as response to an applied electrical signal

I_e, I radiant intensity (of a source, in a given direction)

Quotient of the radiant flux $d\Phi_e$ leaving the source and propagated in the element of solid angle $d\Omega$ containing the given direction, by the element of solid angle

$$I_e = d\Phi_e/d\Omega$$

Unit: $\text{W} \cdot \text{sr}^{-1}$

Note: The radiant intensity I_e of emitters is typically measured with an angle $< 0.01 \text{ sr}$ on mechanical axis or off-axis in the maximum of the irradiation pattern

I_F continuous forward current

The current flowing through a diode in the forward direction

I_{FAV} average (mean) forward current

I_{FM} peak forward current

I_{FSM} surge forward current

I_k short-circuit current

That value of the current which flows when a photovoltaic cell or a photodiode is short circuited ($R_L \ll R_i$) at its terminals

I_o dc output current

I_{ph} photocurrent

That part of the output current of a photoelectric detector, which is caused by incident radiation

I_R reverse current, leakage current

Current which flows through a reverse biased semiconductor pn-junction

IR Abbreviation for infrared

I_{ra} reverse current under irradiation

Reverse light current which flows due to a specified irradiation/illumination in a photoelectric device

$$I_{ra} = I_{ro} + I_{ph}$$

IrDA® Infrared Data Association

No profit organization generating infrared data communication standards

IRED infrared emitting diode

Solid state device embodying a p-n junction, emitting infrared radiation when excited by an electric current. See also LED:

Solid state device embodying a p-n junction, emitting optical radiation when excited by an electric current.

I_{ro} reverse dark current, dark current

Reverse current flowing through a photoelectric device in the absence of irradiation



IrPHY version 1.0

SIR IrDA[®], data communication specification covering data rates from 2.4 kbit/s to 115.2 kbit/s and a guaranteed operating range more than one meter in a cone of $\pm 15^\circ$

IrPHY version 1.1

MIR and FIR were implemented in the IrDA[®] standard with the version 1.1, replacing version 1.0

IrPHY version 1.2

Added the SIR Low Power Standard to the IrDA[®] standard, replacing version 1.1. The SIR Low Power Standard describes a current saving implementation with reduced range (min. 20 cm to other Low Power Devices and min. 30 cm to full range devices).

IrPHY version 1.3

extended the Low Power Option to the higher bit rates of MIR and FIR replacing version 1.2.

IrPHY version 1.4

VFIR was added, replacing version 1.3

I_{SB} **quiescent current**

I_{SD} supply current in dark ambient

I_{SH} supply current in bright ambient

I_v, I **luminous intensity** (of a source, in a given direction)

Quotient of the luminous flux $d\Phi_v$ leaving the source and propagated in the element of solid angle $d\Omega$ containing the given direction, by the element of solid angle

$$I_e = d\Phi_v/d\Omega$$

Unit: $\text{cd} \cdot \text{sr}^{-1}$

Note: The luminous intensity I_v of emitters is typically measured with an angle < 0.01 sr on mechanical axis or off-axis in the maximum of the irradiation pattern

K **luminous efficacy** of radiation

Quotient of the luminous flux Φ_v by the corresponding radiant flux Φ_e :

$$K = \Phi_v / \Phi_e$$

Unit: $\text{lm} \cdot \text{W}^{-1}$

Note: When applied to monochromatic radiations, the maximum value of $K(\lambda)$ is denoted by the symbol K_m

$K_m = 683 \text{ lm} \cdot \text{W}^{-1}$ for $\nu_m = 540 \cdot 10^{12}$ Hz ($\lambda_m \approx 555$ nm) for photopic vision.

$K'_m = 1700 \text{ lm} \cdot \text{W}^{-1}$ for $\lambda'_m \approx 507$ nm for scotopic vision. For other wavelengths:

$$K(\lambda) = K_m V(\lambda) \text{ and } K'(\lambda) = K'_m V'(\lambda)$$

K **kelvin**

SI unit of thermodynamic temperature, is the fraction $1/273.15$ of the thermodynamic tem-

perature of the triple point of water (13th CGPM (1967), Resolution 4). The unit kelvin and its symbol K should be used to express an interval or a difference of temperature.

Note: In addition to the thermodynamic temperature (symbol T), expressed in kelvins, use is also made of Celsius temperature (symbol t) defined by the equation $t = T - T_0$, where $T_0 = 273.15$ K by definition. To express Celsius temperature, the unit "degree Celsius", which is equal to the unit "kelvin" is used; in this case, "degree Celsius" is a special name used in place of "kelvin". An interval or difference of Celsius temperature can, however, be expressed in kelvins as well as in degrees Celsius

Latency

receiver latency allowance (in ms or μs) is the maximum time after a node ceases transmitting before the node's receiving recovers its specified sensitivity

LED and IRED

Light Emitting Diode

LED: Solid state device embodying a p-n junction, emitting optical radiation when excited by an electric current. The term LED is correct only for visible radiation, because light is defined as visible radiation (see "Radiation and Light"). For infrared emitting diodes the term IRED is the correct term. Nevertheless it is common but not correct to use "LED" also for IREDS

$L_e; L$ **radiance** (in a given direction, at a given point of a real or imaginary surface)

Quantity defined by the formula

$$L_e = \frac{d\Phi_v}{dA \cdot \cos \theta \cdot d\Omega}$$

where $d\Phi_e$ is the radiant flux transmitted by an elementary beam passing through the given point and propagating in the solid angle $d\Omega$ containing the given direction; dA is the area of a section of that beam containing the given point; θ is the angle between the normal to that section and the direction of the beam

Unit: $\text{W} \cdot \text{m}^{-2} \cdot \text{sr}^{-1}$

lm **lumen**

Unit for luminous flux

lx **lux**

Unit for illuminance

m **meter**

SI unit of length

M_e ; M **radiant exitance** (at a point of a surface)
 Quotient of the radiant flux $d\Phi_e$ leaving an element of the surface containing the point, by the area dA of that element. Equivalent definition. Integral, taken over the hemisphere visible from the given point, of the expression $L_e \cdot \cos\theta \cdot d\Omega$, where L_e is the radiance at the given point in the various directions of the emitted elementary beams of solid angle $d\Omega$, and θ is the angle between any of these beams and the normal to the surface at the given point.

$$M_e = \frac{d\Phi_e}{dA} = \int_{2\pi sr} L_e \cdot \cos\theta \cdot d\Omega$$

Unit: $W \cdot m^{-2}$

MIR **Medium speed IR**, as SIR, with the data rate 576 kbit/s to 1152 kbit/s

Mode Electrical input or output port of a transceiver device to set the receiver bandwidth

N.A. **Numerical Aperture**

$$N.A. = \sin \alpha/2$$

Term used for the characteristic of sensitivity or intensity angles of fiber optics and objectives

NEP **Noise Equivalent Power**

P_{tot} **total power dissipation**

P_v **power dissipation, general**

Radiation and Light

visible radiation

Any optical radiation capable of causing a visual sensation directly.

Note: There are no precise limits for the spectral range of visible radiation since they depend upon the amount of radiant power reaching the retina and the responsivity of the observer. The lower limit is generally taken between 360 nm and 400 nm and the upper limit between 760 nm and 830 nm

Radiation and Light

optical radiation

Electromagnetic radiation at wavelengths between the region of transition to X-rays ($\lambda = 1$ nm) and the region of transition to radio waves ($\lambda = 1$ mm)

Radiation and Light IR

infrared radiation

Optical radiation for which the wavelengths are longer than those for visible radiation. Note: For infrared radiation, the range between 780 nm and 1 mm is commonly sub-divided into: IR-A 780 nm to 1400 nm

IR-B 1.4 μ m to 3 μ m

IR-C 3 μ m to 1 mm

R_D **dark resistance**

R_F **feedback resistor**

R_i **internal resistance**

R_{is} **isolation resistance**

R_L **load resistance**

R_S **serial resistance**

R_{sh} **shunt resistance**

The shunt resistance of a detector diode is the dynamic resistance of the diode at zero bias. Typically it is measured at a voltage of 10 mV forward or reverse, or peak-to-peak

R_{thJA} **thermal resistance**, junction to ambient

R_{thJC} **thermal resistance**, junction to case

RXD **electrical data output** port of a transceiver device

s **second**

SI unit of time 1 h = 60 min = 3600 s

S **absolute sensitivity**

Ratio of the output value Y of a radiant-sensitive device to the input value X of a physical quantity: $S = Y/X$

Units: E.g. A/lx, A/W, A/(W/m²)

$s(\lambda_p)$ **spectral sensitivity** at a wavelength λ_p

$s(\lambda)$ **absolute spectral sensitivity** at a wavelength λ

The ratio of the output quantity y to the radiant input quantity x in the range of wavelengths λ to $\lambda + \Delta\lambda$:

$$s(\lambda) = dy(\lambda)/dx(\lambda).$$

E.g., the radiant power $\Phi_e(\lambda)$ at a specified wavelength λ falls on the radiationsensitive area of a detector and generates a photocurrent I_{ph} . $s(\lambda)$ is the ratio between the generated photocurrent I_{ph} and the radiant power $\Phi_e(\lambda)$ which falls on the detector:

$$s(\lambda) = I_{ph} / \Phi_e(\lambda)$$

Unit: A/W

$s(\lambda)_{rel}$ **spectral sensitivity, relative**

Ratio of the spectral sensitivity $s(\lambda)$ at any considered wavelength to the spectral sensitivity $s(\lambda_0)$ at a certain wavelength λ_0 taken as a reference:

$$s(\lambda)_{rel} = s(\lambda)/s(\lambda_0)$$

$s(\lambda_0)$ **spectral sensitivity** at a reference wavelength λ_0

SC Electrical input port of a transceiver device to set the receiver sensitivity

SD Electrical input port of a transceiver device to shut down the transceiver

shutdown

Mode of operation where a device is switched to a sleep mode (shut down) by an external signal or after a quiescent period keeping some



functions alive to be prepared for a fast transition to operating mode. Might be in some cases identical with "Standby"

SIR Serial Infrared,

Term used by IrDA[®] to describe infrared data transmission up to and including 115.2 kbit/s. SIR IrDA[®] data communication covers 2.4 kbit/s to 115.2 kbit/s, equivalent to the basic serial infrared standard introduced with the physical layer version IrPhy version 1.0

split power supply

Term for using **separated power supplies** for different functions in transceivers. Receiver circuits need well-controlled supply voltages. IRED drivers don't need a controlled supply voltage but need much higher currents. Therefore it saves cost not to control the IRED current supply and have a separated supply. For that some modified design rules have to be taken into account for designing the ASIC. This is used in nearly all Vishay transceivers and is described in US-Patent No. 6,157,476

sr steradian (sr)

SI unit of solid angle Ω

Solid angle that, having its vertex at the centre of a sphere, cuts off an area of the surface of the sphere equal to that of a square with sides of length equal to the radius of the sphere. (ISO, 31/1-2.1, 1978)

Example:

The unity solid angle, in terms of geometry, is the angle subtended at the center of a sphere by an area on its surface numerically equal to the square of the radius (see figures below) Other than the figures might suggest, the shape of the area doesn't matter at all. Any shape on the surface of the sphere that holds the same area will define a solid angle of the same size. The unit of the solid angle is the **steradian (sr)**. Mathematically, the solid angle is dimensionless, but for practical reasons, the steradian is assigned

Standby

Mode of operation where a device is prepared to be quickly switched into an idle or operating mode by an external signal

T period of time (duration)

T temperature

0 K = - 273.15 °C

Unit: K (kelvin)

t temperature

°C (degree Celsius)

Instead of t sometimes T is used not to mix up temperature T with time t

t time

T_{amb} ambient temperature

If self-heating is significant: temperature of the surrounding air below the device, under conditions of thermal equilibrium. If self-heating is insignificant: air temperature in the surroundings of the device

T_{amb} ambient temperature range

As an absolute maximum rating: The maximum permissible ambient temperature range

T_C temperature coefficient

The ratio of the relative change of an electrical quantity to the change in temperature (ΔT) which causes it under otherwise constant operating conditions

T_C colour temperature (BE)

The temperature of a Planckian radiator whose radiation has the same chromaticity as that of a given stimulus

Unit: K

Note: The **reciprocal colour temperature** is also used, unit K^{-1} (BE)

T_{case} case temperature

The temperature measured at a specified point on the case of a semiconductor device. Unless otherwise stated, this temperature is given as the temperature of the mounting base for devices with metal can

t_d delay time

t_f fall time

The time interval between the upper specified value and the lower specified value on the trailing edge of the pulse.

Note: It is common to use a 90 % value of the signal for the upper specified value and a 10 % value for the lower specified value

T_j junction temperature

The spatial mean value of the temperature during operation. In the case of phototransistors, it is mainly the temperature of the collector junction because its inherent temperature is the maximum

t_{off} turn-off time

t_{on} turn-on time

t_p pulse duration

The time interval between the specified value on the leading edge of the pulse and the specified value on the trailing edge of the output pulse

	Note: In most cases the specified value is 50 % of the signal	ΔV_O	output voltage change (differential output voltage)
t_{pi}	input pulse duration	V_{OC}	open circuit voltage The voltage measured between the photovoltaic cell or photodiode terminals at a specified irradiance/illuminance (high impedance voltmeter!)
t_{po}	output pulse duration	V_{OH}	output voltage high
t_r	rise time The time interval between the lower specified value and the upper specified value on the trailing edge of the pulse. Note: It is common to use a 90 % value of the signal for the upper specified value and a 10 % value for the lower specified value	V_{OL}	output voltage low
t_s	storage time	V_{ph}	photovoltage The voltage generated between the photovoltaic cell or photodiode terminals due to irradiation/ illumination
T_{sd}	soldering temperature Maximum allowable temperature for soldering with a specified distance from the case and its duration	V_R	reverse voltage (of a junction) Applied voltage such that the current flows in the reverse direction
T_{stg}	storage temperature range The temperature range at which the device may be stored or transported without any applied voltage	V_R	reverse (breakdown) voltage The voltage drop which results from the flow of a defined reverse current
TXD	Electrical data input port of a transceiver device	V_S	supply voltage
V	volt	V_{SS}	(most negative) supply voltage (in most cases: Ground)
$V(\lambda)$	standard luminous efficiency function for photopic vision (relative human eye sensitivity)	$\pm \varphi_{1/2}$	angle of half transmission distance
$V(\lambda), V'(\lambda)$	spectral luminous efficiency (of a monochromatic radiation of wavelength λ); $V(\lambda)$ for photopic vision; $V'(\lambda)$ for scotopic vision) Ratio of the radiant flux at wavelength λ_m to that at wavelength λ such that both radiations produce equally intense luminous sensations under specified photometric conditions and λ_m is chosen so that the maximum value of this ratio is equal to 1.	η	quantum efficiency
V_{CC}	supply voltage (positive)	$\theta_{1/2}; \pm \varphi = \alpha/2$	half – intensity angle In a radiation diagram, the angle within which the radiant (or luminous) intensity is greater than or equal to half of the maximum intensity. Note: IEC60747-5-1 is using $\theta_{1/2}$. In Vishay data sheets mostly $\pm \varphi = \alpha/2$ is used
V_{CEsat}	collector-emitter saturation voltage The saturation voltage is the dc voltage between collector and emitter for specified (saturation) conditions, i.e., I_C and E_V (E_e or I_B), whereas the operating point is within the saturation region	$\theta_{1/2}; \pm \varphi = \alpha/2$	half – sensitivity angle In a sensitivity diagram, the angle within which the sensitivity is greater than or equal to half of the maximum sensitivity. Note: IEC60747-5-1 is using $\theta_{1/2}$. In Vishay data sheets mostly $\pm \varphi = \alpha/2$ is used
V_{dd}	supply voltage (positive)	Ω	solid angle , see sr, steradian for IEC60050(845)-definition The space enclosed by rays, which emerge from a single point and lead to all the points of a closed curve. If it is assumed that the apex of the cone formed in this way is the center of a sphere with radius r and that the cone intersects with the surface of the sphere, then the size of the surface area (A) of the sphere subtending the cone is a measure of the solid angle Ω $\Omega = A/r^2$ The full sphere is equivalent to 4π sr. A cone with an angle of $\alpha/2$ forms a solid angle
V_F	forward voltage The voltage across the diode terminals which results from the flow of current in the forward direction		
VFIR	As SIR, data rate 16 Mbit/s		
V_{logic}	reference voltage for digital data communication ports		
V_O	output voltage		

of $\Omega = 2\pi(1 - \cos \alpha/2) = 4\pi \sin^2 \alpha/4$
Unit: sr (steradian)

λ_m **wavelength** of the maximum of the spectral luminous efficiency function $V(\lambda)$

$\Delta\lambda$ **range of spectral bandwidth (50 %)**
The range of wavelengths where the spectral sensitivity or spectral emission remains within 50 % of the maximum value

$\Phi_e; \Phi, P$ **radiant flux; radiant power**
Power emitted, transmitted or received in the form of radiation.
Unit: W
W = Watt

$\Phi_v; \Phi$ **luminous flux**
Quantity derived from radiant flux Φ_e by evaluating the radiation according to its action upon the CIE standard photometric observer. For photopic vision

$$\Phi_v = K_m \int_0^\infty \frac{d\Phi_e \lambda}{d\lambda} \cdot V(\lambda) d\lambda \quad ,$$

where $\frac{d\Phi_e \lambda}{d\lambda}$ is the spectral distribution of

the radiant flux and $V(\lambda)$ is the spectral luminous efficiency.

Unit : lm

lm: lumen

$K_m = 683 \text{ lm/W}$:

Note: For the values of K_m (photopic vision) and K'_m (scotopic vision), see IEC60050 (845-01-56).

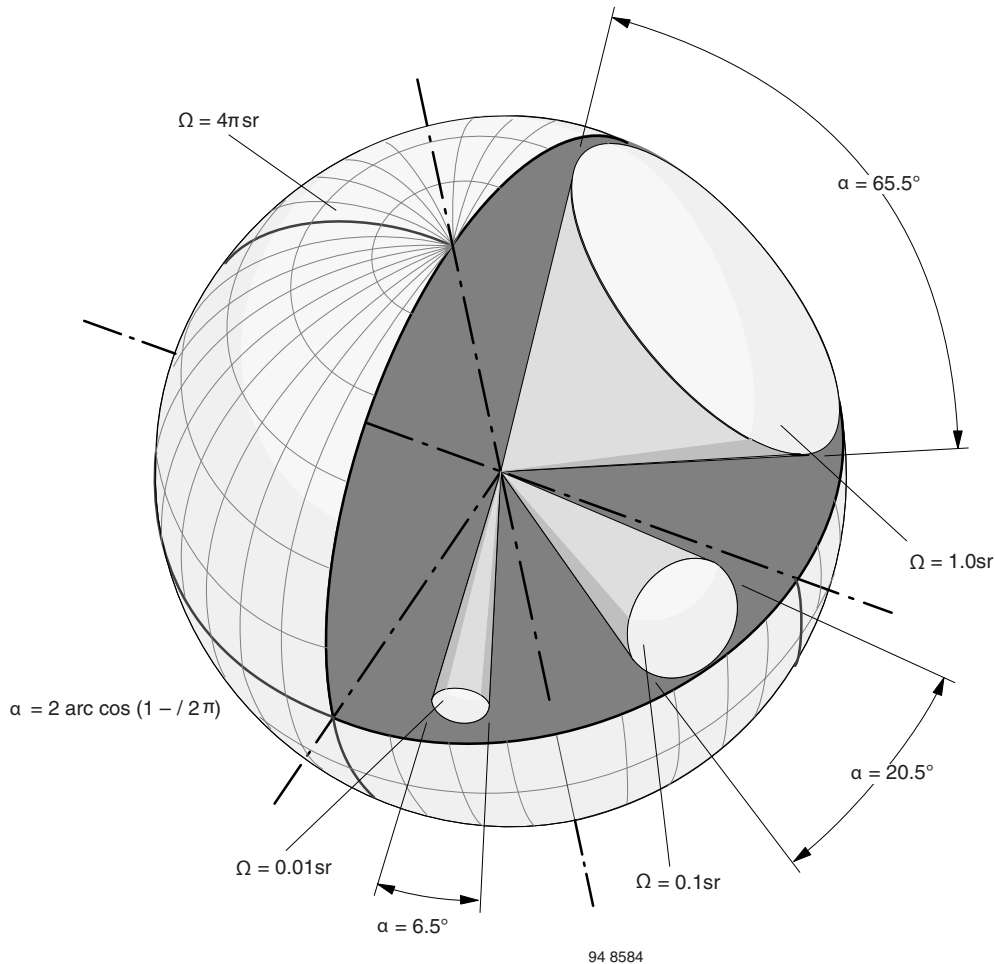
λ **wavelength**, general

λ_c **centroid wavelength**
Centroid wavelength λ_c of a spectral distribution, which is calculated as "centre of gravity wavelength" according to

$$\lambda_c = \frac{\int_{\lambda_1}^{\lambda_2} \lambda \cdot S_x(\lambda) d\lambda}{\int_{\lambda_1}^{\lambda_2} S_x(\lambda) d\lambda}$$

λ_D **dominant wavelength**

λ_p **wavelength** of peak sensitivity or peak emission



Definitions

Databook Nomenclature

The nomenclature and usage of symbols, abbreviations and terms inside the Vishay Semiconductors IRDC Databook is based on ISO and IEC standards. The special optoelectronic terms and definitions are referring to the IEC Multilingual Dictionary (Electricity, Electronics and Telecommunications), Fourth edition (2001-01), IEC50 (Now: IEC60050). The references are taken from the current editions of IEC60050 (845), IEC60747-5-1 and IEC60747-5-2. Measurement conditions are based on IEC and other international standards and especially guided by IEC60747-5-3.

Editorial notes: Due to typographical limitations variables cannot be printed in an italics format, which is usually mandatory. Our databook in general is using American spelling (AE). International standards are

written in British English (BE). Definitions are copied without changes from the original text. Therefore these may contain British spelling.

Radiant and Luminous Quantities and Their Units

These two kinds of quantities have the same basic symbols, identified respectively, where necessary, by the subscript e (energy) or v (visual), e.g. Φ_e , Φ_v . See note.

Note: Photopic and scotopic quantities. - Luminous (photometric) quantities are of two kinds, those used for photopic vision and those used for scotopic vision. The wording of the definitions in the two cases being almost identical, a single definition is generally sufficient with the appropriate adjective, photopic or scotopic added where necessary.

The symbols for scotopic quantities are prime (Φ'_v , I'_v , etc), but the units are the same in both cases.

In general, optical radiation is measured in radiometric units. Luminous (photometric) units are used when optical radiation is weighted by the sensitivity of the human eye, correctly spoken, by the CIE standard photometric observer (Ideal observer having a relative spectral responsivity curve that conforms to the $V(\lambda)$ function for photopic vision or to the $V'(\lambda)$ function for scotopic vision, and that complies with the summation law implied in the definition of luminous flux).

Note: With a given spectral distribution of a radiometric quantity the equivalent photometric quantity can be evaluated. However, from photometric units without knowing the radiometric spectral distribution in general one cannot recover the radiometric quantities.

Radiometric Terms, Quantities and Units

Photometric Term	Equivalent Radiometric Term	Symbol	Unit	Reference
Luminous power or Luminous flux	Radiant power or Radiant flux Φ_e	Φ_v	lm	Φ_v : IEC50 (845-01-25) lm: IEC50 (845-01-51)
Luminous intensity	Radiant intensity I_e	I_v	lm/sr = cd	I_v : IEC50 (845-01-31) cd: IEC50 (845-01-50)
Illuminance	Irradiance E_e	E_v	lm/m ² = lx (Lux)	E_v : IEC50 (845-01-38) lx: IEC50 (845-01-52)
Luminous exitance	Radiant exitance M_e	M_v	lm/m ²	IEC50 (845-01-48)
Luminance	Radiance L_e	L_v	cd/m ²	IEC50 (845-01-35)

Table 2: Photometric Quantities and Units

Photometric units are derived from the radiometric units by weighting them with a wavelength dependent standardized human eye sensitivity $V(\lambda)$ - function, the so-called CIE-standard photometric observer. There are different functions for photopic vision ($V(\lambda)$) and scotopic vision ($V'(\lambda)$).

In the following is shown, how the luminous flux is derived from the radiant power and its spectral distribution. The equivalent other photometric terms can be derived from the radiometric terms in the same way.

Relation between distance r , irradiance (illuminance) E_e (E_v) and intensity I_e (I_v)

The relation between intensity of a source and the resulting irradiance in the distance r is given by the basic square root rule law.

An emitted intensity I_e generates in a distance r the irradiance $E_e = I_e/r^2$.

This relationship is not valid under near field conditions and should be used not below a distance d smaller than 5 times the emitter source diameter.

The radiometric terms are used to describe the quantities of optical radiation.

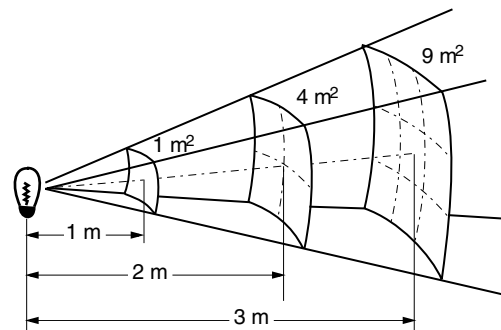
The relevant radiometric units are:

Radiometric Term	Symbol	Unit	Reference
Radiant power, Radiant flux	Φ_e	W	IEC50 (845-01-24)
Radiant intensity	I_e	W/sr	IEC50 (845-01-30)
Irradiance	E_e	W/m ²	IEC50 (845-01-37)
Radiant Exitance	M_e	W/m ²	IEC50 (845-01-47)
Radiance	L_e	W/(sr·m ²)	IEC50 (845-01-34)

Table 1: Radiometric Quantities and Units

Photometric Terms, Quantities and Units

The photometric terms are used to describe the quantities of optical radiation in the wavelength range of visible radiation (generally assumed as the range



18145

Using a single radiation point source, one gets the following relation between the parameter E_e , Φ_e , r .

$$E_e = \frac{d\Phi_e}{dA} \left[\frac{W}{m^2} \right]$$

use

$$I_e = \frac{d\Phi}{d\Omega}, \quad \Omega = \frac{A}{r^2} \quad \text{and get}$$

$$E_e = \frac{d\Phi_e}{dA} = I_e \frac{d\Omega}{dA} = \frac{I_e}{r^2} \left[\frac{W}{m^2} \right]$$

Examples

1. Calculate the irradiance with given intensity and distance r .

Transceivers with specified intensity of $I_e = 100 \text{ mW/sr}$ will generate in a distance of 1 m an irradiance of $E_e = 100/1^2 = 100 \text{ mW/m}^2$. In a distance of 10 m the irradiance would be $E_e = 100/10^2 = 1 \text{ mW/m}^2$.

2. Calculate the range of a system with given intensity and irradiance threshold.

When the receiver is specified with a sensitivity threshold irradiance $E_e = 20 \text{ mW/m}^2$, the transmitter with an intensity $I_e = 120 \text{ mW/sr}$ the resulting range can be calculated as

$$r = \sqrt{\frac{I_e}{E_e}} = \sqrt{\frac{120}{20}} = \sqrt{6} = 2.45 \text{ m}$$